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PATENT NUMBER and  
ISSUE DATE

U.S. UTILITY Patent Application

APPL NUM 10008812	FILING DATE 11/13/2001	CLASS 117	SUBCLASS -	GAU 1765	EXAMINER
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\*\*APPLICANTS: Mutti Paolo, Veronkov Vladimir

\*\*CONTINUING DATA VERIFIED:  
THIS APPLICATION IS A CON OF 09/455 563 02/01/2000

\*\* FOREIGN APPLICATIONS VERIFIED:

PG-PUB	DO NOT PUBLISH <input type="checkbox"/>	RESCIND <input type="checkbox"/>	ATTORNEY DOCKET NO
Foreign priority claimed		yes <input type="checkbox"/> no <input type="checkbox"/>	MEMOTP935751 (2053-4)
35 USC 119 conditions met		yes <input type="checkbox"/> no <input type="checkbox"/>	
Verified and Acknowledged by Principal Applicant			
TITLE : Method for controlling growth of a silicon crystal to minimize growth rate and diameter deviations			

NOTICE OF ALLOWANCE MAILED		CLAIMS ALLOWED	
		Total Claims	Print Claim for O.G.
ISSUE FEE		DRAWING	
Amount Due	Date Paid	Sheets Drwg.	Figs.Drwg. Print Fig.
<input type="checkbox"/> <b>TERMINAL DISCLAIMER</b>		Application Examiner	
		<b>PREPARED FOR ISSUE</b> <b>WARNING:</b> The information disclosed herein may be restricted. Unauthorized disclosure may be prohibited by the United States Code Title 35, Sections 122, 181 and 368, Possession outside the U.S. Patent & Trademark Office is restricted to authorized employees and contractors only.	
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